

# **N-Channel RF Amplifier**

This device is designed for HF/VHF mixer/amplifier and applications where Process 50 is not adequate. Sufficient gain and low noise for sensitive receivers. Sourced from Process 90.

### Absolute Maximum Ratings\* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{DG}$	Drain-Gate Voltage	25	V
$V_{GS}$	Gate-Source Voltage	- 25	V
I <sub>GF</sub>	Forward Gate Current	10	mA
T <sub>J</sub> ,T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

# **Thermal Characteristics**

Thermal Characteristics TA = 25°C unless otherwise noted				
Symbol	Characteristic		Мах	Units
		J210-212	*MMBFJ210-212	
PD	Total Device Dissipation	350	225	mW
	Derate above 25°C	2.8	1.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W

\*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

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J210/J211/J212/MMBFJ210/J211/J212, Rev A

# **N-Channel RF Amplifier**

-2.5V

2.0

3.0

4.0

5.0

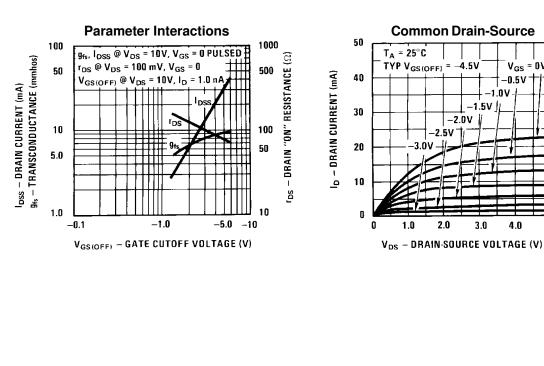
3.0V

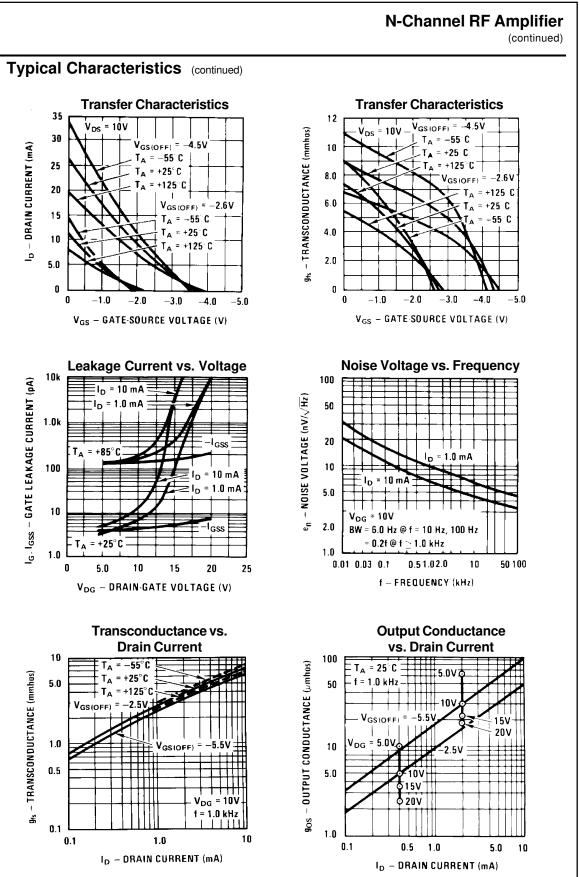
1.0

(continued)

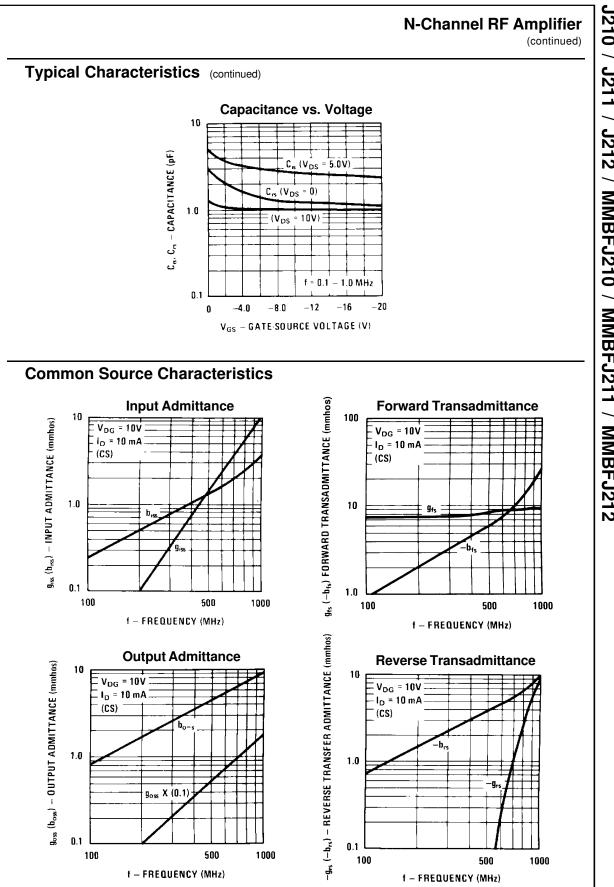
Symbol	Parameter	Test Conditions		Min	Max	Units
	RACTERISTICS				-	
V <sub>(BR)GSS</sub>	Gate-Source Breakdown Voltage	$I_{G} = 1.0 \ \mu A, \ V_{DS} = 0$		- 25		V
l <sub>GSS</sub>	Gate Reverse Current	$V_{GS} = 15 V, V_{DS} = 0$			- 100	pA
$V_{GS(off)}$	Gate-Source Cutoff Voltage		210 211	-1.0 - 2.5	-3.0 - 4.5	V V
			212	- 4.0	- 6.0	v
ON CHAR	ACTERISTICS					
IDSS	Zero-Gate Voltage Drain Current*	$V_{DS} = 15 V, V_{GS} = 0$	210	2.0	15	m A
			211 212	7.0 15	20 40	m A m A
goss	Transconductance Common Source Output Conductance		210 211 212 Hz	4000 6000 7000	12,000 12,000 12,000 200	µmhos µmhos µmhos µmhos
Puise rest. Puis	se Width ≤300 μS					
Туріса	al Characteristics					
	Parameter Interactions	1000 50 <b>C</b> c	ommo	n Drai	n-Sourc	:e

# J210 / J211 / J212 / MMBFJ210 / MMBFJ211 / MMBFJ212

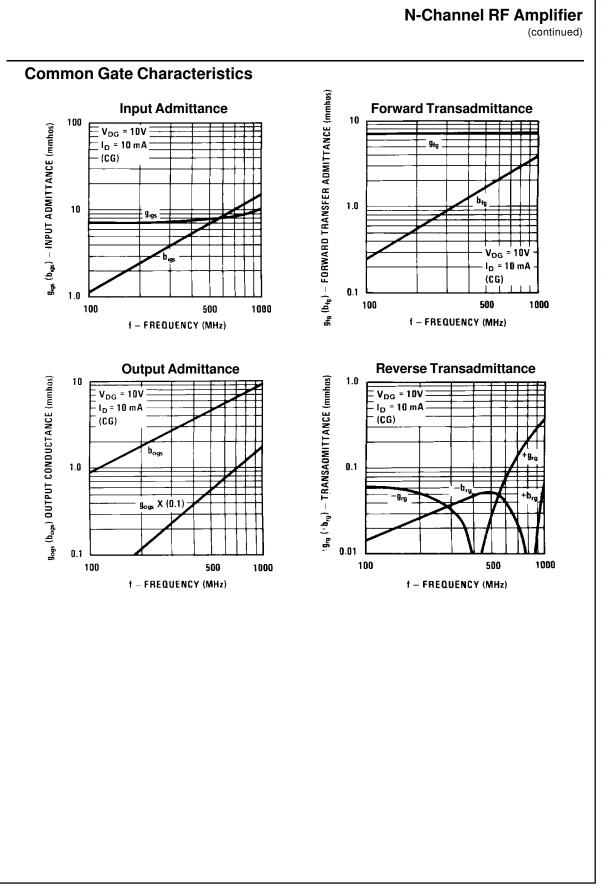












J210 / J211 / J212 / MMBFJ210 / MMBFJ211 / MMBFJ212

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